## (12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

# (19) World Intellectual Property Organization International Bureau



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# (43) International Publication Date 28 June 2001 (28.06.2001)

### **PCT**

# (10) International Publication Number WO 01/47044 A3

- (51) International Patent Classification7: 21/311
- H01L 51/40,
- (21) International Application Number: PCT/GB00/04940
- (22) International Filing Date:

21 December 2000 (21.12.2000)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data:

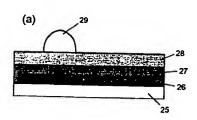
9930217.6 0009917.6 21 December 1999 (21.12.1999) GE 20 April 2000 (20.04.2000) GE

(71) Applicant (for all designated States except US): PLAS-TIC LOGIC LIMITED [GB/GB]: Sheraton House, Castle Park, Cambridge CB3 0AX (GB).

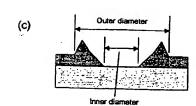
- (72) Inventors; and
- (75) Inventors/Applicants (for US only): SIRRINGHAUS, Henning [DE/GB]; Churchill College. Cambridge CB3 0DS (GB). FRIEND, Richard, Henry [GB/GB]: 37 Barton Road, Cambridge CB3 9LG (GB). KAWASE, Takeo [JP/GB]: 18 Eachard Road, Cambridge CB3 6HY (GB).
- (74) Agents: SLINGSBY, Philip, Roy et al.: Page White & Farrer, 54 Doughty Street, London WCIN 2LS (GB).
- (81) Designated States (national): AE. AG. AL. AM. AT. AU. AZ. BA. BB. BG, BR, BY. BZ. CA. CH, CN. CR. CU. CZ. DE. DK. DM. DZ. EE. ES. FI. GB. GD. GE. GH. GM. HR. HU, ID. IL. IN, IS. JP. KE, KG, KP. KR, KZ, LC, LK. LR. LS. LT, LU. LV. MA. MD. MG. MK. MN. MW. MX. MZ. NO. NZ. PL. PT. RO. RU. SD. SE, SG. SI. SK. SL. TJ. TM. TR. TT, TZ, UA, UG. US, UZ, VN, YU. ZA. ZW.
- (84) Designated States (regional): ARIPO patent (GH. GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZW). Eurasian

[Continued on next page]

### (54) Title: FORMING INTERCONNECTS



(57) Abstract: A method for forming an electronic device, comprising: forming a first conductive or semiconductive layer; forming a sequence of at least one insulating layer and at least one semiconducting layer over the first conductive or semiconductive layer; locally depositing solvents at a localised region of the insulating layer so as to dissolve the sequence of insulating and semiconducting layers in the region to leave a void extending through the sequence of layers; and depositing conductive or semiconductive material in the void.



140
PVP 250nm
120 layer, 250nm
750nm
Outer diameter
0 5 10 15 20 25 30 35 40
Diameter of Drop (micron)

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patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM). European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR). OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG).

#### Published:

- with international search report

(88) Date of publication of the international search report: 6 December 2001

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

Internal Application No PC1/GB 00/04940

		PC1	/GB 00/04940
a. classif IPC 7	HO1L51/40 H01L21/311		
According to	International Patent Classification (IPC) or to both national classification	ation and IPC	
B. FIELDS			
Minimum do IPC 7	cumentation searched (classification system followed by classification HO1L	on symbols)	
Documentati	ion searched other than minimum documentation to the extent that s	uch documents are included in th	ne fields searched
	ata base consulted during the international search (name of data base), EPO-Internal	se and, where practical, search to	erms used)
C. DOCUME	ENTS CONSIDERED TO BE RELEVANT		
Category *	Citation of document, with indication, where appropriate, of the rek	evant passages	Relevant to claim No.
Х	WO 99 10939 A (KONINKL PHILIPS ELECTRONICS NV ;PHILIPS AB (SE)) 4 March 1999 (1999-03-04) the whole document		44-48
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		-/	
X Furt	ner documents are listed in the continuation of box C.	X Patent family members	are listed in annex.
"A" document defining the general state of the art which is not considered to be of particular relevance "E" earlier document but published on or after the international filling date "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "O" document referring to an oral disclosure, use, exhibition or other means "P" document published prior to the international filling date but later than the priority date claimed		T later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention  "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone  "I" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.  "8." document member of the same patent family	
Date of the actual completion of the international search  19 February 2001		Date of mailing of the international search report  1 8, 05, 01	
Name and mailing address of the ISA  European Patent Office, P.B. 5818 Patentiaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3018		Authorized officer  Königstein,	c

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PCI/GB 00/04940

C.(Continue	ation) DOCUMENTS CONSIDERED TO BE RELEVANT	101/40 00/04340		
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ational application No. PCT/GB 00/04940

(I Observations where certain claims were found unsearchable (Continuation of item 1 of first sheet)				
This International Search Report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:				
1. Claims Nos.: because they relate to subject matter not required to be searched by this Authority, namely:				
2. Claims Nos.: because they relate to parts of the International Application that do not comply with the prescribed requirements to such an extent that no meaningful International Search can be carried out, specifically:				
3. Claims Nos.: because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).				
Box II Observations where unity of invention is lacking (Continuation of item 2 of first sheet)				
This International Searching Authority found multiple inventions in this International application, as follows:				
see additional sheet				
As all required additional search fees were timely paid by the applicant, this International Search Report covers all searchable claims.				
2. As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.				
3. As only some of the required additional search fees were timely paid by the applicant, this International Search Report covers only those claims for which fees were paid, specifically claims Nos.:				
4.  No required additional search fees were timely paid by the applicant. Consequently, this International Search Report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.:  1-38,44-49				
Remark on Protest  The additional search fees were accompanied by the applicant's protest.  No protest accompanied the payment of additional search fees.				

## FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

This International Searching Authority found multiple (groups of) inventions in this international application, as follows:

1. Claims: 1-38,44-49

Patterning of organic insulating layers by selective etching

The prior Art describes a field effect transistor substantially consisting of organic materials.

The new features mentioned in claims 1-38 are contact holes, made in organic dielectric layers by wet etching using an ink-jet printing system to locally suply the etch liquid.

From this we can formulate an objective problem of making contact holes in organic dielectric layers by wet etching using an ink-jet printing system to locally suply the etch liquid.

The special technical features, as defined in Rule 13(2) PCT, are contact holes, made in organic dielectric layers by wet etching using an ink-jet printing system to locally suply the etch liquid.

2. Claims: 39-43

Selective doping of organic insulating layers

The prior Art describes a field effect transistor substantially consisting of organic materials.

The new features mentioned in claims 1-38 are conductive (interconnection) patterns made by selective doping organic insulating layers to make them conductive. The dopants are applied using an ink-jet printing system.

From this we can formulate an objective problem of making conductive patterns made by selective doping organic insulating layers to make them conductive, applying the dopants are using an ink-jet printing system.

The special technical features, as defined in Rule 13(2) PCT, are conductive (interconnection) patterns made by selective doping organic insulating layers to make them conductive. The dopants are applied using an ink-jet printing system.

autormation on patent family members

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